ELEC-313 Lab 2: Diode Characterization

September 20, 2013

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- 1 Objective
- 2 Schematics

Circuit Tested

Test Configuration

- 3 Procedure
- 4 Results
- 4.1 Part A

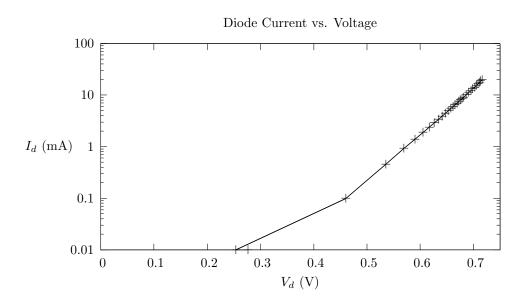


Figure 1: Diode characteristics measured in Part A.

- 4.2 Part B
- 5 Conclusion
- 6 Appendix

Equations

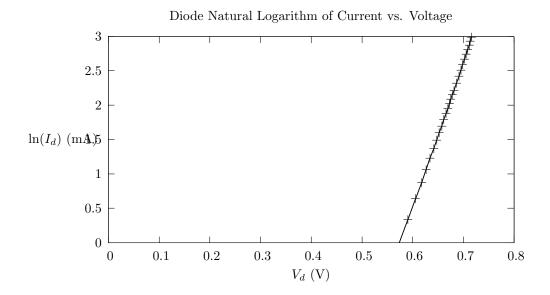


Figure 2: $\ln(I_d)$ vs. V_d .

$R(\Omega)$	V_d (V)	$I_d (\mathrm{mA})$
200	0.751	46.00
500	0.713	18.60
1k	0.682	9.30
2k	0.650	4.70
5k	0.605	1.85
10k	0.571	0.94
20k	0.538	0.47
50k	0.494	0.19
100k	0.464	0.10

Table 1: Diode characteristics measured in Part B.

$$\begin{array}{c|cccc} V_d \; ({\rm V}) & I_d \; ({\rm mA}) & V_{OC} \; ({\rm V}) \\ \hline 0.712 & 27.2 & 6.70 \\ \end{array}$$

Table 2: Diode characteristics measured in Part C.